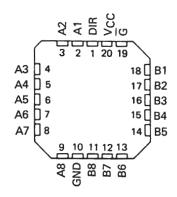
- SN74LS64X-1 Versions Rated at I_{OL} of 48 mA
- Bi-directional Bus Transceivers in High-Density 20-Pin Packages
- Hysteresis at Bus Inputs Improves Noise Margins
- Choice of True or Inverting Logic
- Choice of 3-State or Open-Collector Outputs

DEVICE	OUTPUT	LOGIC
'LS640	3-State	Inverting
'LS641	Open-Collector	True
'LS642	Open-Collector	Inverting
'LS644	Open-Collector	True and inverting
'LS645	3-State	True

SN54LS' J PACKAGE SN74LS' DW OR N PACKAGE
(TOP VIEW)

DIR	1	\cup	20	□vcc
	2		19	ŪĞ
A2[3		18] B1
A3[4		17	B 2
A4[5		16	ВЗ
A5[6		15	B 4
A6[7		14	B 5
A7[8		13	B 6
A8[9		12	B7
GND	10	C	11	B8
	L		-	1

SN54LS' . . . FK PACKAGE (TOP VIEW)



FUNCTION TABLE

CON	NTROL		OPERATION			
INPUTS		'LS640	'LS641			
G	DIR	'LS642	'LS645	'LS644		
L	L	B data to A bus	B data to A bus	B data to A bus		
L	н	A data to B bus	A data to B bus	Ā data to B bus		
н	х	Isolation	Isolation	Isolation		

H = high level, L= low level, X = irrelevant

description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. The devices transmit data from the A bus to the B bus or from the B bus to the A bus depending upon the level at the direction control (DIR) input. The enable input (\overline{G}) can be used to disable the device so the buses are effectively isolated.

The -1 versions of the SN74LS640 thru SN74LS642, SN74LS644, and SN74LS645 are identical to the standard versions except that the recommended maximum I_{OL} is increased to 48 milliamperes. There are no -1 versions of the SN54LS640 thru SN54LS642, SN54LS644, and SN54LS645.

The SN54LS640 thru SN54LS642, SN54LS644, and SN54LS645 are characterized for operation over the full military temperature range of -55 °C to 125 °C. The SN74LS640 thru SN74LS642, SN74LS644, and SN74LS645 are characterized for operation from 0 °C to 70 °C.

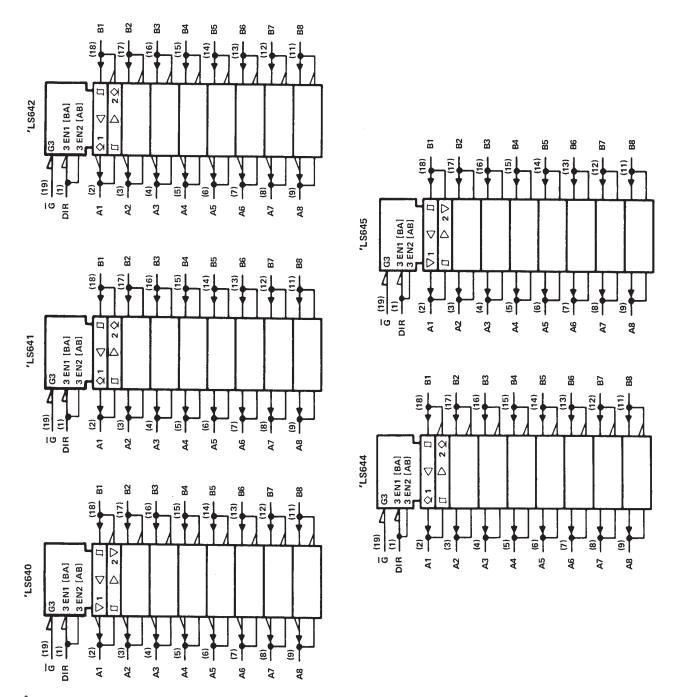
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



SN54LS640 THRU SN54LS642, SN54LS644, SN54LS645 SN74LS640 THRU SN74LS642, SN74LS644, SN74LS645 **OCTAL BUS TRANSCEIVRS**

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logic symbols[†]



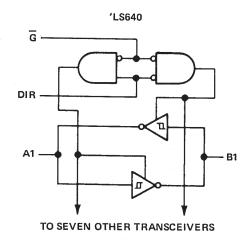
[†] These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for DW, J, and N packages.

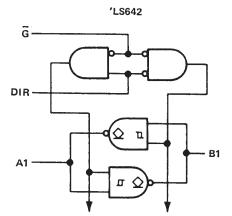


SN54LS640 THRU SN54LS642, SN54LS644, SN54LS645 SN74LS640 THRU SN74LS642, SN74LS644, SN74LS645 **OCTAL BUS TRANSCEIVRS**

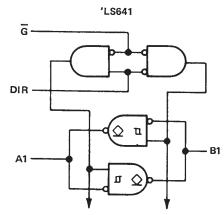
SDLS189 - APRIL 1979 - REVISED MARCH 1988

logic diagrams (positive logic)

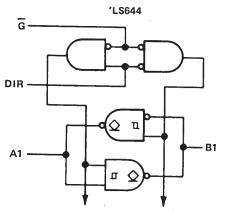




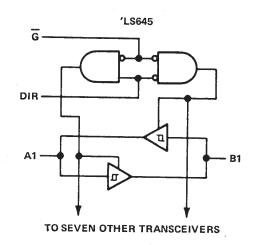




TO SEVEN OTHER TRANSCEIVERS



TO SEVEN OTHER TRANSCEIVERS





SN54LS640, SN54LS645 SN74LS640, SN74LS645 OCTAL BUS TRANSCEIVRS WITH 3-STATE OUTPUTS

SDLS189 – APRIL 1979 – REVISED MARCH 1988

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC} (see Note 1) 7 V
Input voltage: All inputs
I/O ports
Operating free-air temperature range: SN54LS640, SN54LS645 55°C to 125°C
SN74LS640, SN74LS645
Storage temperature range

NOTE 1: Voltage values are with respect to network ground terminal.

recommended operating conditions

	PARAMETER		SN54LS640 SN54LS645			SN74LS640 SN74LS645			
		MIN	NOM	MAX	MIN	NOM	MAX		
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V	
ViH	High-lvel input voltage	2			2			V	
VIL	Low-level input voltage			0.5			0.6	V	
ЮН	High-level output current			- 12			- 15	mA	
IOL	Low-level output current			12			24		
							48†	mA	
ТА	Operating free-air temperature	- 55		125	0		70	°C	

[†]The 48-mA limit applies for the SN74LS640-1 and SN74LS645-1 only.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		Т	TEST CONDITIONS [‡]			SN54LS640 SN54LS645			SN74LS640 SN74LS645			
					MIN	түр§	MAX	MIN	ТҮР§	MAX		
VIK		V _{CC} = MIN,	l ₁ = – 18 mA				- 1.5			- 1.5	V	
Hyste (V _{T+} –	eresis - V _T _)	V _{CC} = MIN,		A or B input	0.1	0.4		0.2	0.4		v	
∨он		V _{CC} = MIN,	V _{IH} = 2 V,	IOH = - 3 mA	2.4	3.4		2.4	3.4			
*0H		VIL = MAX		IOH = MAX	2			2			1	
		$V_{OO} = MIN$	V _{IH} = 2 V,	1 _{0L} = 12 mA		0.25	0.4		0.25	0.4	v	
VOL		$V_{1L} = MAX$		IOL = 24 mA					0.35	0.5		
				IOL = 48 mA #					0.4	0.5	1	
IOZH		00	Ğat2V,	V _O = 2.7 V			20			20	μA	
IOZL		V _{CC} = MAX,	Ĝat 2 V,	V _O = 0.4 V			- 0.4			- 0.4	mA	
ų.	A or B	V _{CC} = MAX		V ₁ ≈ 5.5 V			0.1			0.1		
	DIR or G	VCC MAA		V ₁ = 7 V			0.1			0.1	mA	
ΗΗ		V _{CC} = MAX,	V _{IH} = 2.7 V				20			20	μA	
ΗL		V _{CC} = MAX,	V _{IL} = 0.4 V				- 0.4			- 0.4	mA	
los¶		V _{CC} = MAX			- 40		- 225	- 40		- 225	mA	
	Outputs high					48	70		48	70	1	
ICC	Outputs low	V _{CC} = MAX,	Outputs open			62	90		62	90	mA	
	Outputs at Hi-Z					64	95		64	95	1	

[†]For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. [§]All typical values are at $V_{CC} = 5 V$, $T_{A} = 25 °C$.

[¶]Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second. [#]The 48-mA condition applies for the SN74LS640-1 and SN74LS645-1 only.



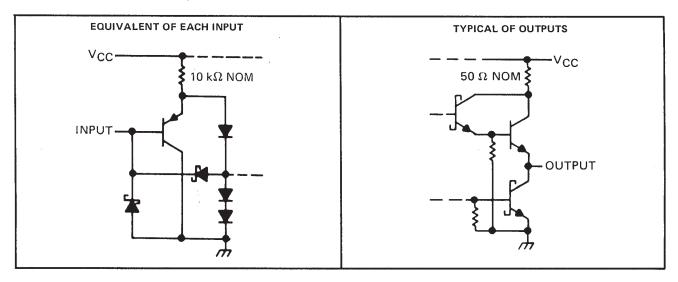
SN54LS640, SN54LS645 SN74LS640, SN74LS645 OCTAL BUS TRANSCEIVRS WITH 3-STATE OUTPUTS SDLS189 – APRIL 1979 – REVISED MARCH 1988

	PARAMETER		то	TEST	'LS640, 'LS640-1		'LS64	15, 'LSE	645-1	UNIT	
	PARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	MIN	ТҮР	MAX	MIN	ТҮР	MAX	UNIT
+	Propagation delay time,	А	В			6	10		8	15	
^t PLH	low-to-high-level output	В	A			6	10		8	15	ns
+	Propagation delay time,	А	В	C		8	15		11	15	
^t PHL	high-to-low-level output	В	A	$C_{L} = 45 \text{ pF},$		8	15		11	15	ns
+	Output enable time to	G	A	R _L = 667 Ω, See Note 2		31	40		31	40	
tPZL	low level	G	В	See Note 2		31	40		31	40	ns
	Output enable time to	G	A			23	40		26	40	
^t PZH	high level	G	В			23	40		26	40	ns
.	Output disable time	Ğ	А	0 5 - 5		15	25		15	25	
^t PLZ	from low level	G	В	$C_L = 5 pF$,		15	25		15	25	ns
	Output disable time	G	А	$R_{L} = 667 \ \Omega,$		15	25		15	25	
^t PHZ	from high level	G	В	See Note 2		15	25		15	25	ns

switching characteristics, V_{CC} = 5 V, T_A = $25 \,^{\circ}$ C

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

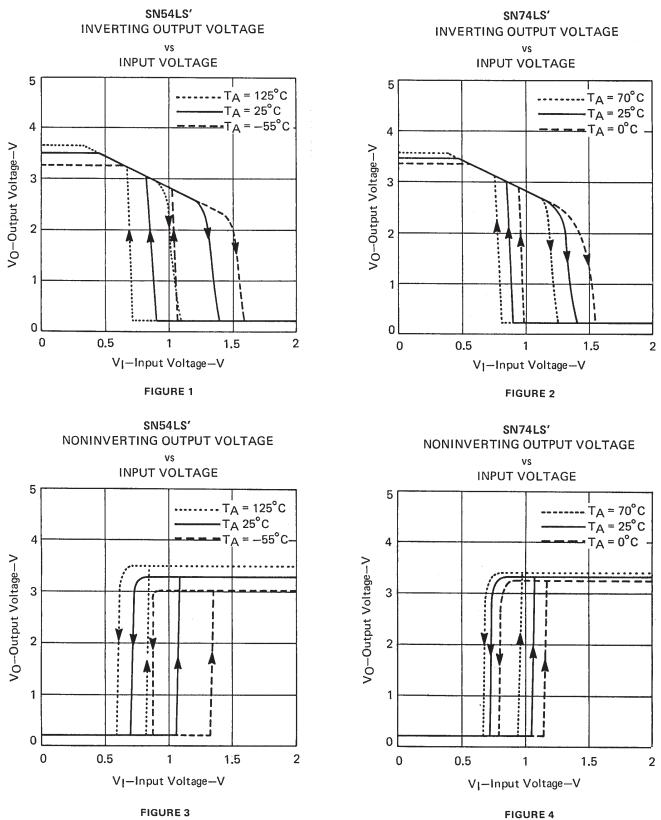
schematics of inputs and outputs





SN54LS640, SN54LS645 SN74LS640, SN74LS645 OCTAL BUS TRANSCEIVRS WITH 3-STATE OUTPUTS SDLS189 – APRIL 1979 – REVISED MARCH 1988

TYPICAL CHARACTERISTICS





SN54LS641, SN54LS642, SN54LS644 SN74LS641, SN74LS642, SN74LS644 OCTAL BUS TRANSCEIVRS WITH OPEN-COLLECTOR OUTPUTS SDLS189 - APRIL 1979 - REVISED MARCH 1988

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC} (see Note 1) Input voltage: All inputs and I/O ports	7V
	/V
Operating free-air temperature range: SN54LS641, SN54LS642, SN54LS644	C to 125°C
SN74LS641, SN74LS642, SN74LS644)° C to 70° C
Storage temperature range $\ldots \ldots - 65^\circ$	C to 150° C

NOTE 1: Voltage values are with respect to network ground terminal.

recommended operating conditions

PARAMETER	S	N54LS6 N54LS6	642	s	N74LS6 N74LS6 N74LS6	642	UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	1
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH High-level input voltage	2			2		·	V
VIL Low-level input voltage			0.5			0.6	V
V _{OH} High-level output voltage			5.5			5.5	V
IOL Low-level output current			12			24	
						48 §	' mA
T _A Operating free-air temperature	- 55		125	0		70	°C

The 48 mA limit applies for the SN74LS641-1, SN74LS642-1, and SN74LS644-1 only.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST COM	TEST CONDITIONS [†]			SN54LS641 SN54LS642 SN54LS644			SN74LS641 SN74LS642 SN74LS644		
	·			MIN	TYP‡	MAX	MIN	TYP‡	MAX		
VIK		V _{CC} = MIN,	lj = — 18 mA			- 1.5			- 1.5	V	
Hysteres (V _{T+} – V-		V _{CC} = MIN,	A or B input	0.1	0.4		0.2	0.4		v	
юн		V _{CC} = MIN, VIL = MAX,	V _{IH} = 2 V, V _{OH} = 5.5 V			0.1			0.1	mA	
		V _{CC} = MIN,	1 _{0L} = 12 mA		0.25	0.4		0.25	0.4		
VOL		V _{IH} = 2 V,	IOL = 24 mA					0.35	0.5	v	
		VIL = MAX	I _{OL} = 48 mA§					0.4	0.5		
4	A or B	V _{CC} = MAX	Vj = 5.5 V			0.1			0.1		
·'I	DIR or G		V _I = 7 V			0.1			0.1	mA	
Чн		V _{CC} = MAX,	V _I = 2.7 V			20			20	μA	
ЧL		V _{CC} = MAX,	V ₁ = 0.4 V			- 0.4			- 0.4	mA	
	Outputs high				48	70	·	48	70		
ICC	Outputs low	V _{CC} = MAX,	Outputs open		62	90		62	90	mA	
	Outputs at Hi-Z				64	95		64	95		

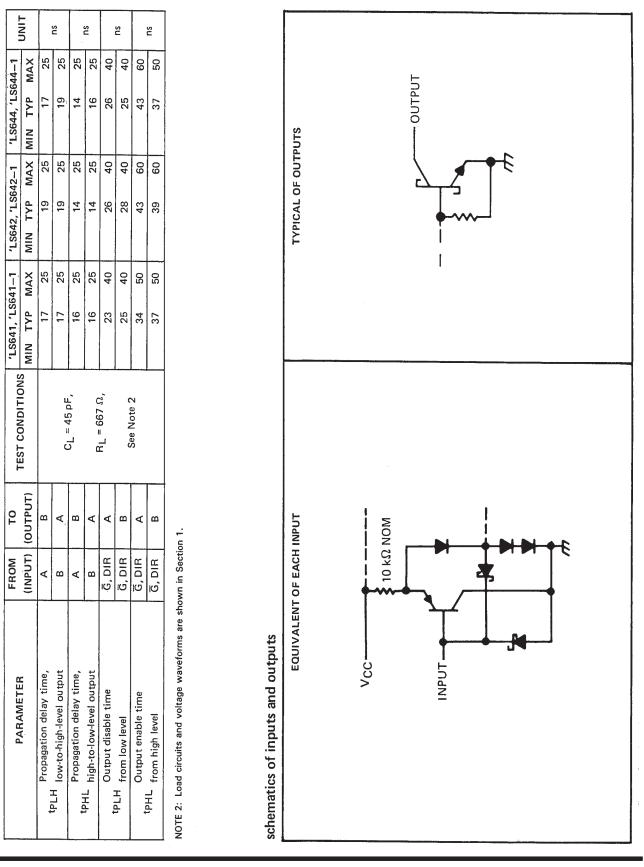
[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C. §The 48 mA condition applies for the SN74LS641-1, SN74LS642-1, and SN74LS644-1 only.



SN54LS641, SN54LS642, SN54LS644 SN74LS641, SN74LS642, SN74LS644 OCTAL BUS TRANSCEIVRS WITH OPEN-COLLECTOR OUTPUTS

SDLS189 - APRIL 1979 - REVISED MARCH 1988





switching characteristics at VCC = 5 V, $TA = 25^{\circ}C$



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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
5962-8416101VRA	ACTIVE	CDIP	J	20	20	TBD	A42	N / A for Pkg Type	
5962-8416101VSA	ACTIVE	CFP	W	20	25	TBD	Call TI	N / A for Pkg Type	
84161012A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Call TI	
8416101RA	ACTIVE	CDIP	J	20	1	TBD	Call TI	Call TI	
8416101SA	ACTIVE	CFP	W	20	1	TBD	Call TI	Call TI	
SN54LS640J	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
SN54LS645J	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
SN74LS640-1DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640-1DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640-1DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640-1DWR	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	
SN74LS640-1N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS640-1NE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS640-1NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640-1NSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640-1NSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74LS640DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS640N3	OBSOLETE	PDIP	Ν	20		TBD	Call TI	Call TI	
SN74LS640NE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS640NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640NSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS640NSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641-1DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641-1DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641-1DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641-1DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641-1DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641-1DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641-1N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS641-1N3	OBSOLETE	PDIP	Ν	20		TBD	Call TI	Call TI	
SN74LS641-1NE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS641DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641DWR	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI	
SN74LS641DWRE4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI	
SN74LS641DWRG4	ACTIVE	SOIC	DW	20		TBD	Call TI	Call TI	



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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74LS641N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS641N3	OBSOLETE	PDIP	Ν	20		TBD	Call TI	Call TI	
SN74LS641NE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS641NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641NSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS641NSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS642-1DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS642-1DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS642-1DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS642-1N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS642-1NE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS642DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS642DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS642DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS642N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS642NE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS642NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS642NSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS642NSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS644-1N	OBSOLETE	PDIP	Ν	20		TBD	Call TI	Call TI	
SN74LS644N	OBSOLETE	PDIP	Ν	20		TBD	Call TI	Call TI	
SN74LS645-1DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74LS645-1DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645-1DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645-1DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645-1DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645-1DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645-1N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS645-1N3	OBSOLETE	PDIP	Ν	20		TBD	Call TI	Call TI	
SN74LS645-1NE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS645-1NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645-1NSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645-1NSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645DWR	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	
SN74LS645N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS645N3	OBSOLETE	PDIP	Ν	20		TBD	Call TI	Call TI	
SN74LS645NE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74LS645NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645NSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LS645NSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SNJ54LS640FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	
SNJ54LS640J	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
SNJ54LS640W	ACTIVE	CFP	W	20	1	TBD	Call TI	N / A for Pkg Type	
SNJ54LS645FK	NRND	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	
SNJ54LS645J	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
SNJ54LS645W	OBSOLETE	CFP	W	20		TBD	Call TI	Call TI	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF SN54LS640, SN54LS640-SP, SN54LS645, SN74LS640, SN74LS645 :

Catalog: SN74LS640, SN54LS640, SN74LS645





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17-Aug-2012

• Military: SN54LS640, SN54LS645

• Space: SN54LS640-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

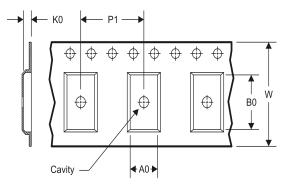
REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

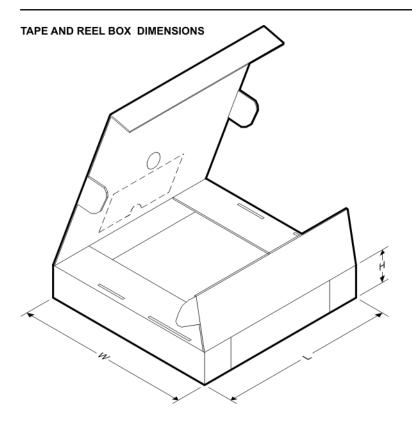
*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LS640-1NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74LS640DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74LS640NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74LS641-1DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74LS641NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74LS642NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74LS645-1DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74LS645-1NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74LS645NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1

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PACKAGE MATERIALS INFORMATION



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LS640-1NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LS640DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LS640NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LS641-1DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LS641NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LS642NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LS645-1DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LS645-1NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LS645NSR	SO	NS	20	2000	367.0	367.0	45.0

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only.
 - E. Falls within Mil-Std 1835 GDFP2-F20



LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N**) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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